What can the UW do for the DOE CC program?

David Larbalestier, Eric Hellstrom, Chang-Beom Eom, Alex Gurevich, Anatoly Polyanskii and Mark Rzchowski

Guidelines for University Presenters

- The goal of this workshop is to identify the developments that are necessary to enable the fabrication of long-length coated conductors with good performance. The purpose of this session is to show how the research programs and facilities at universities can be applied toward that goal.
- Your talk should focus on how the research and facilities at your university can help meet the goal of producing long-length conductors with good performance. During your talk, please try to address the following questions: How does your research apply to the on-going efforts at the national laboratories and in industry? Does your research apply to one specific process or is it broadly applicable to the various processes for producing coated conductors? Are there new ideas or directions that should be pursued? If so, how will these new ideas assist our efforts to reach our goal?
- Other topics that you should consider and be prepared to discuss, but which should not be the focus of your talk, include: How would proprietary information be handled? Would public disclosure of information through publications and presentations be a necessity? Are there opportunities to combine our efforts with those sponsored by other agencies, e.g. the Air Force?

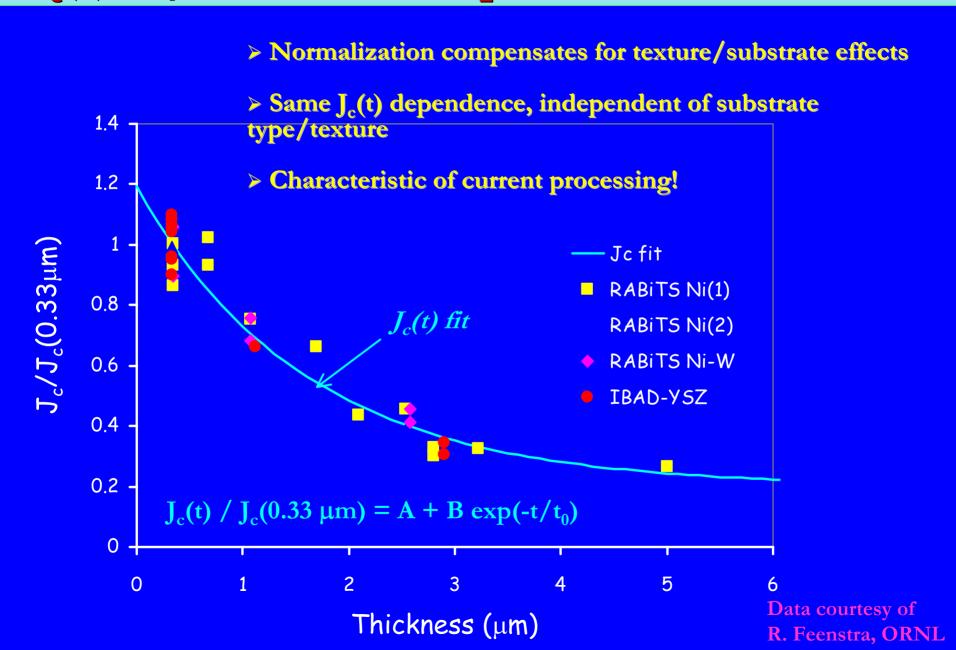
Motivating Interests

- Film growth by chemical and PVD routes
- Theory coupled to experiment
- Advanced superconducting and microstructural characterizations
- Conductors, their stability and protection
 - Metallic buffers
 - Interface resistance YBCO/stabilizer
- Collaborations

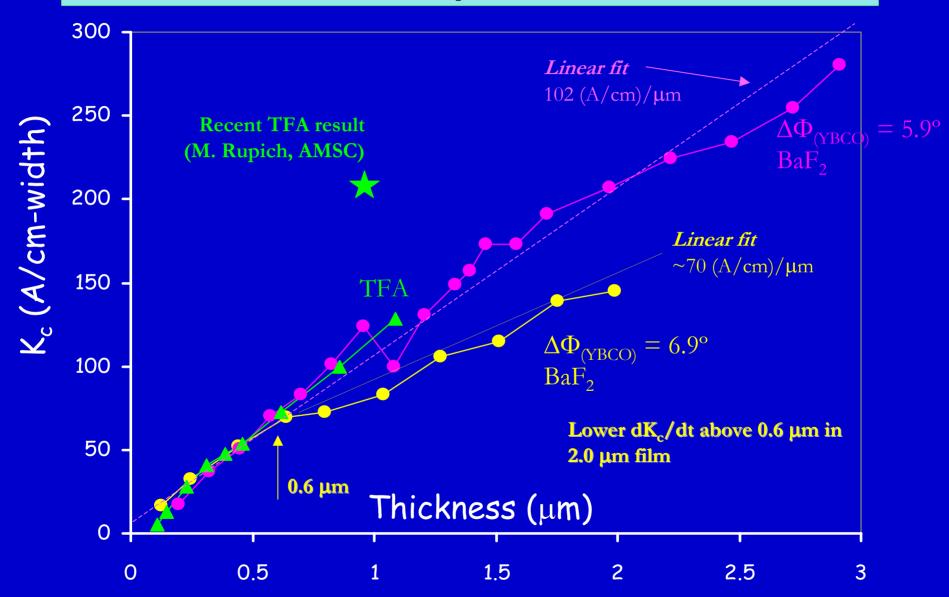
Thickness Dependence of Jc(H)

- November 2001 visit to ANL, LANL and ORNL (Oberly, Weinstock, Larbalestier) to find out key issues
- Much in hand Jc(t) not
- Organized 2 hr meeting at St Pete 2002
- Nucleated 3 MURI experimental efforts to amplify earlier LANL study
 - Addition of theory component (Gurevich)

J_c(t) dependence in BaF₂ YBCO - variable t films



Through thickness milling experiments shows ~ linear dependence of Ic on t

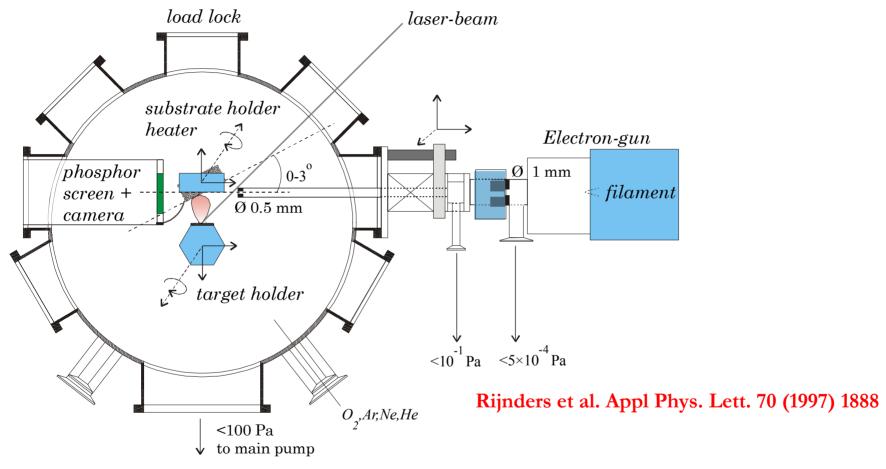


Jc(t) experiment

- Done on 2 ex situ CC
 - BaF₂ on IBAD-YSZ
 - MOD on RABiTS Ni-W
- Both show quasi-linear dependence of Ic on t
 - Very good news for high current conductors
- ◆ BUT...
 - Jc is constant at ~1MA/cm², even at 0.3 μm, not 3 MA/cm²
- Epitaxy of growth may be crucial, especially disruptions at cap-YBCO interface
- Transport magneto-optics to be added to throughthickness milled samples

Larbalestier group

Pulsed Laser Deposition System with in situ High Pressure RHEED

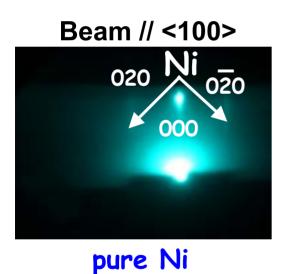


We used this system to monitor the oxygen c(2x2) reconstructed surface and deposit epitaxial $SrTiO_3$ buffer layer and YBCO superconductor.

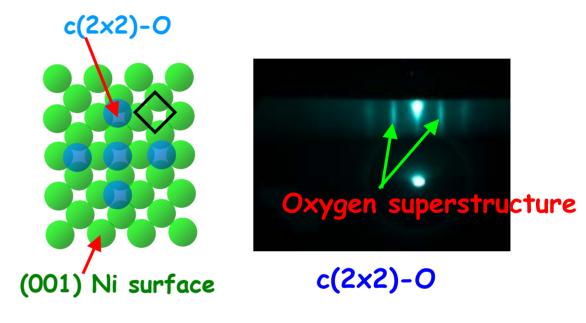
Works up to 1 Torr O_2

Eom group

Pure Ni surface without c(2x2) superstructure



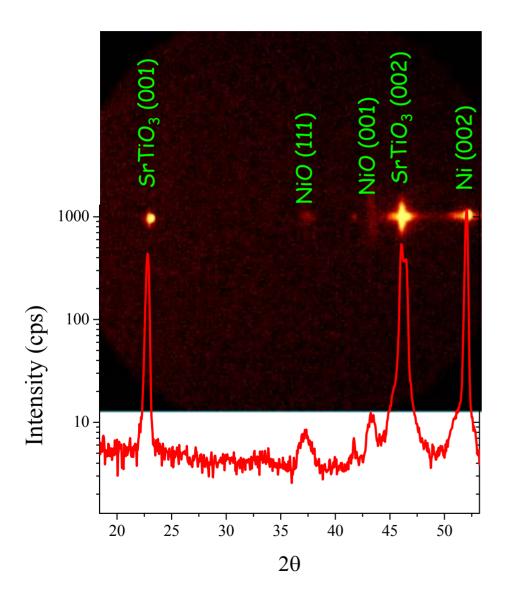
c(2x2)-Oxygen superstructure



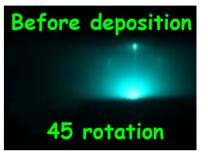
Ni

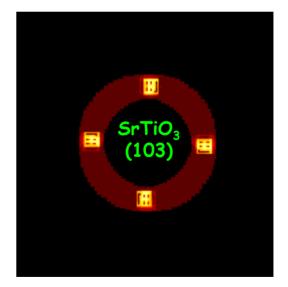
We were able to grow epitaxial $SrTiO_3$ buffer layer only on this surface but not on pure Ni. - See next view graph.

$SrTiO_3$ layer deposited on Ni with c(2x2)-oxygen superstructure shows perfect epitaxy



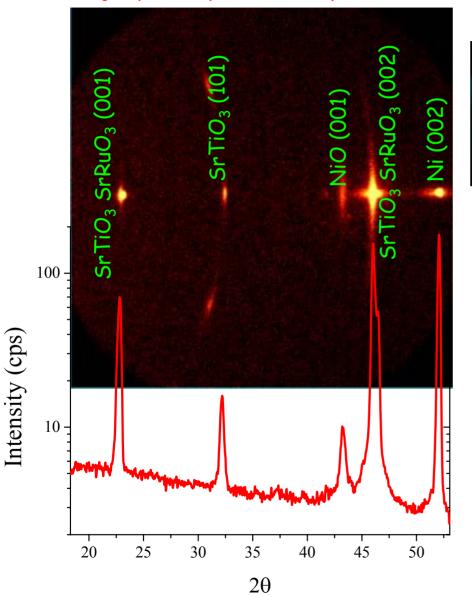


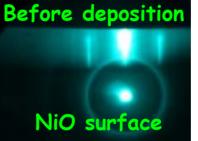


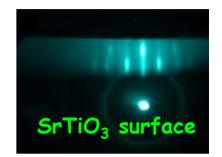


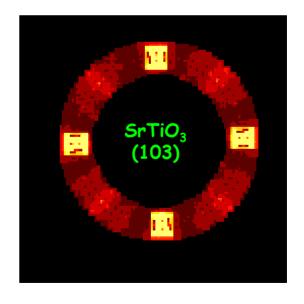
In contrast,

$SrTiO_3$ layer deposited on pure Ni without c(2x2)-oxygen shows bad texture









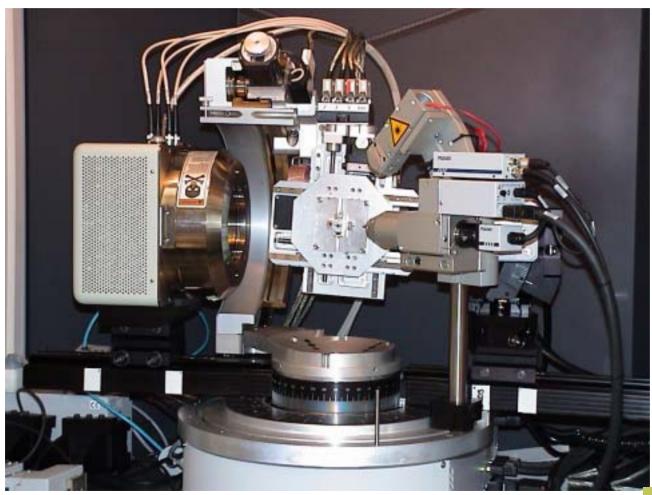
RHEED patterns during the growth of epitaxial YBCO/SrRuO3/SrTiO3 on Epitaxial Ni Thin Film on (001) SrTiO₃ Substrate
Oxygen c (2x2) 020 020 reconstruction **YBCO** SRuO₃ buffer SrTiO3 seed Epitaxial Ni (001) SrTiO₃ substrate Before deposition Pure Ni surface

SrRuO₃

SrTiO₃

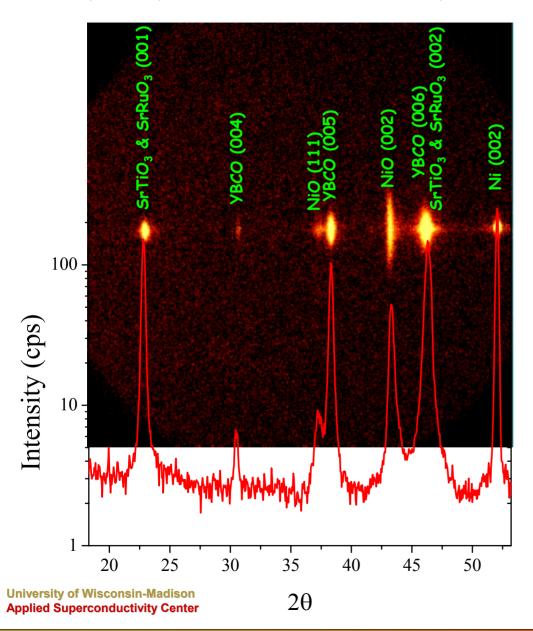
YBCO

Variable Temperature (6.5K - 900C) Four-circle x-ray diffraction system with 2-D area detector Microdiffraction - 50 microns



Eom group

Texture of YBCO/SrRuO $_3$ /SrTiO $_3$ on epitaxial Ni studied by x-ray diffraction – This shows perfect epitaxy of all three lavers







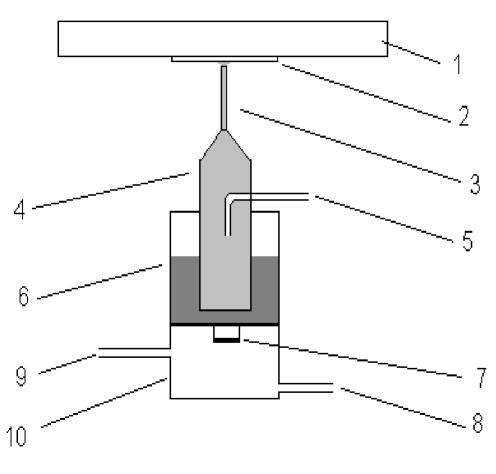


In-plane Pole Figure

Aerosol Spray Pyrolysis (ASP) of oxide layers - buffers and Y-123

- Inexpensive, rapid solution method to form epitaxial oxide layers
- Spray mist (~5μm droplets) of solution onto heated substrate (~900°C)
- Oxide forms directly on heated substrate

ASP system is simple, inexpensive, and operates at atmospheric pressure



- 1. Resistive heating plate
- 2. Substrate
- 3. Quartz nozzle
- 4. Mist chamber
- 5. Carrier gas inlet
- 6. Solution tank
- 7. Transducer
- 8. Cooling water inlet
- 9. Cooling water outlet
- 10. Cooling tank

Hellstrom group

Benefits of ASP

- Deposit simple or complicated oxides -CeO₂ to Y-123
 - Change chemistry during deposition
- Inexpensive solutions
 - from metals, oxides, nitrates, carbonates, or acetates
- Rapid 17nm/s
 - Reducing conditions for buffers
 - Oxidizing conditions for Re-123

Two European groups doing ASP

- F. Weiss St. Martin d'Hères, France
 - * Y₂O₃ buffer layer on LAO
 - * Y-123 on Ag
 - * (Hg,Re)-1223 on MgO
- ◆ J. MacManus-Driscoll, Imperial College
 - Y-123 on LAO, MgO, and Ag

 No reports of buffer or Y-123 on Ni (or Cu) substrate

Hellstrom group

Summary - what can we offer?

- Certain unique capabilities
 - PLD chamber with high pressure RHEED
 - ASP capability for whole stack growth
 - Modeling from deep understanding of solid state and conductor stability
 - Broad and deep superconducting and microstructural characterization capabilities - nV V-I, magneto optics, scanning laser microscopy forthcoming, high resolution microscopy
- Applicability to RABiTS, IBAD and other CC
- Multidisciplinary and highly interactive
 - With each other and with the labs, industry and MURI partners
 - We enjoy this!